TOSHIBA INSULATED GATE BIPOLAR TRANSISTOR SILICON N CHANNEL IGBT

GT50J301

HIGH POWER SWITCHING APPLICATIONS MOTOR CONTROL APPLICATIONS

• Third generation IGBT

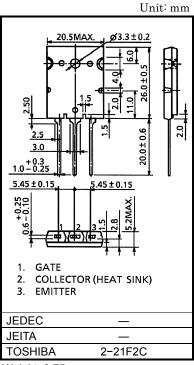
• Enhancement mode type

 $\begin{array}{ll} \bullet & \mbox{High speed} & \vdots \ t_f = 0.30 \mu s \ (\mbox{Max.}) \\ \bullet & \mbox{Low saturation voltage} & \vdots \ \mbox{VCE } \ (\mbox{sat)} = 2.7 \ (\mbox{Max.}) \\ \end{array}$

• FRD included between emitter and collector

MAXIMUM RATINGS (Ta = 25°C)

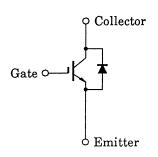
CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	600	V	
Gate-Emitter Voltage		V _{GES}	±20	V	
Collector Current	DC	I _C	50	А	
	1ms	I _{CP}	100		
Forward Current	DC	IF	50	А	
	1ms	I _{FM}	100		
Collector Power Dissipation (Tc = 25°C)		P _C	200	W	
Junction Temperature		Tj	150	°C	
Storage Temperature		T _{stg}	-55~150	°C	
Screw Torque		_	0.8	N · m	

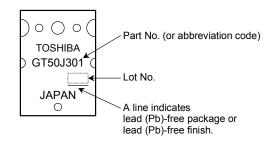


Weight: 9.75 g

EQUIVALENT CIRCUIT

MARKING

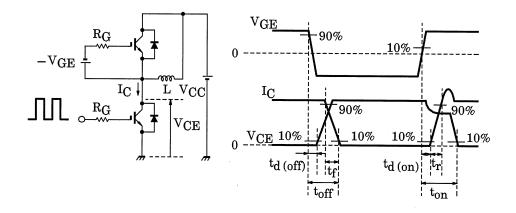


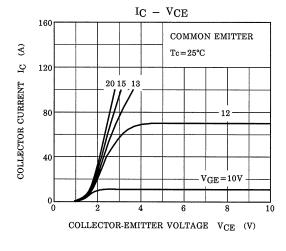


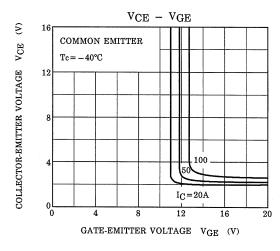
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

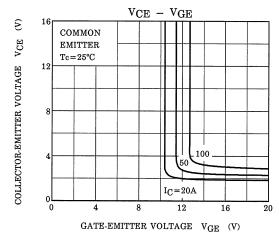
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Gate Leakage Current		I _{GES}	V _{GE} = ±20V, V _{CE} = 0	_	_	±500	nA
Collector Cut-off Current		I _{CES}	V _{CE} = 600V, V _{GE} = 0	_	_	1.0	mA
Gate-Emitter Cut-off Voltage		V _{GE (OFF)}	I _C = 5mA, V _{CE} = 5V	5.0	7.0	8.0	V
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 50A, V _{GE} = 15V	_	2.1	2.7	V
Input Capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0 f = 1MHz	_	4500	_	pF
Switching Time	Turn-on delayTime	t _{d (on)}		_	0.08	_	- μs
	Rise Time	t _r	Inductive Load $V_{CC} = 300V$ $V_{GE} = \pm 15V$ $I_{C} = 50A$ $R_{G} = 24\Omega$ (Note 1)	_	0.12	_	
	Turn-on Time	t _{on}		_	0.40	_	
	Turn-off delayTime	t _{d (off)}		_	0.20	_	
	Fall Time	t _f		_	0.15	0.30	
	Turn-off Time	t _{off}		_	0.50	_	
Forward Voltage		VF	I _F = 50A, V _{GE} = 0	_	2.4	3.5	V
Reverse Recovery Time		t _{rr}	I _F = 50A, V _{GE} = 10V di / dt = 100A / μs	_	0.1	0.2	μs
Thermal Resistance		R _{th (j-c)}	IGBT	_	_	0.625	°C/W
Thermal Resistance		R _{th (j-c)}	DIODE	_	_	2.50	°C/W

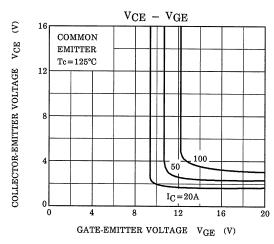
Note 1: Switching time measurement circuit and input / output waveforms

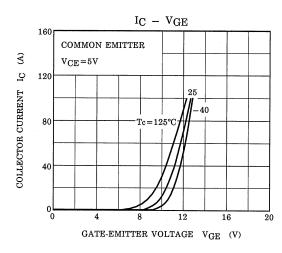


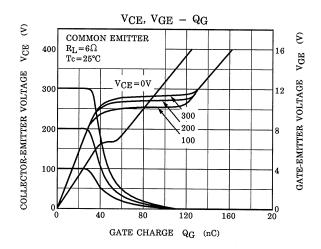


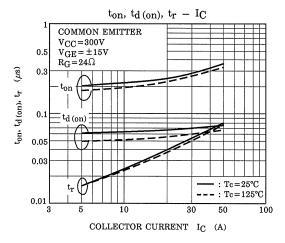


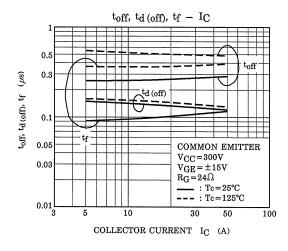


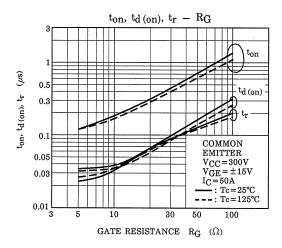


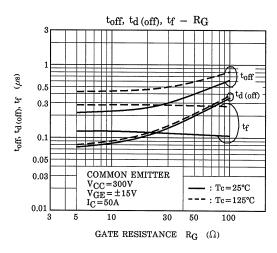


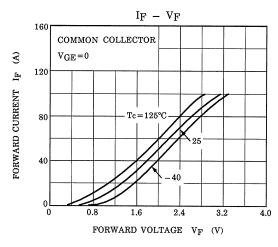


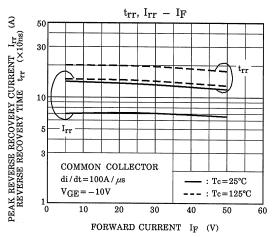


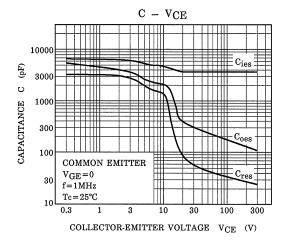


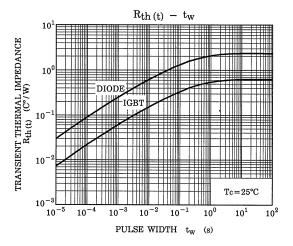


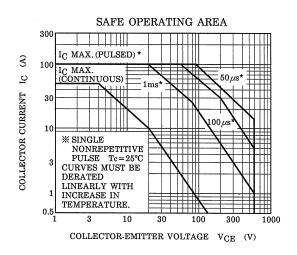


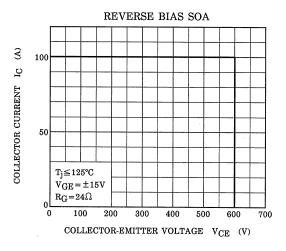












RESTRICTIONS ON PRODUCT USE

Handbook" etc..

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.

3 2004-07-06